

**Features**

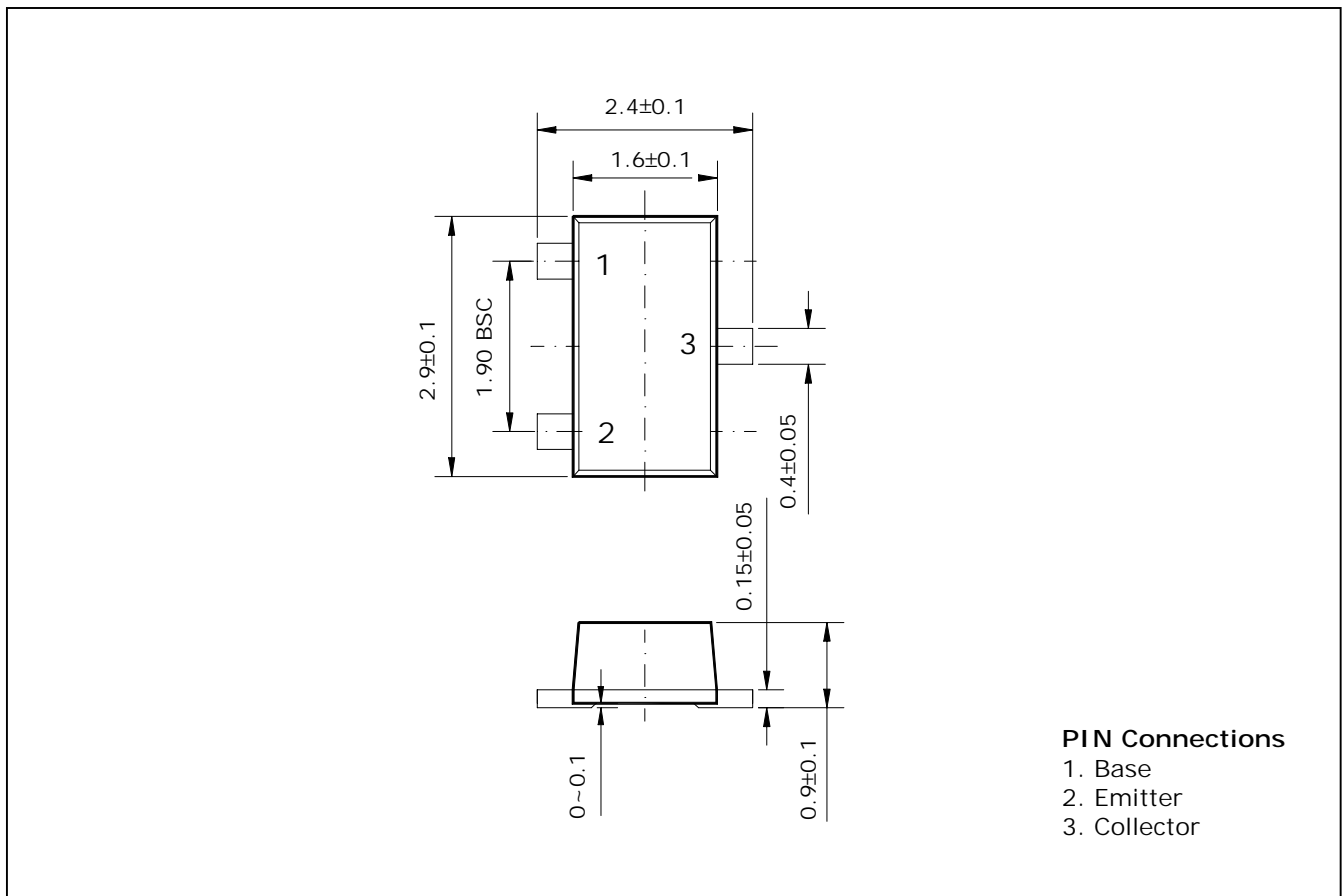
- Extremely low collector-to-emitter saturation voltage  
( $V_{CE(SAT)} = -0.15V$  Typ. @ $I_C/I_B = -100mA/-10mA$ )
- Suitable for low voltage large current drivers
- Excellent  $h_{FE}$  Linearity
- Complementary pair with DN030S
- Switching Application

**Ordering Information**

Type NO.	Marking	Package Code
DP030S	P01	SOT-23F

**Outline Dimensions**

**unit : mm**



**Absolute maximum ratings**

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	$V_{CBO}$	-15	V
Collector-Emitter voltage	$V_{CEO}$	-12	V
Emitter-Base voltage	$V_{EBO}$	-5	V
Collector current	$I_C$	-300	mA
Collector dissipation	$P_C$	200	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 ~ 150	°C

**Electrical Characteristics**

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base breakdown voltage	$BV_{CBO}$	$I_C = -50\mu A, I_E = 0$	-15	-	-	V
Collector-Emitter breakdown voltage	$BV_{CEO}$	$I_C = -1mA, I_B = 0$	-12	-	-	V
Emitter-Base breakdown voltage	$BV_{EBO}$	$I_E = -50\mu A, I_C = 0$	-5	-	-	V
Collector cut-off current	$I_{CBO}$	$V_{CB} = -12V, I_E = 0$	-	-	-0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -5V, I_C = 0$	-	-	-0.1	$\mu A$
DC current gain	$h_{FE1}$	$V_{CE} = -1V, I_C = -100mA$	200	-	450	-
	$h_{FE2}$	$V_{CE} = -1V, I_C = -300mA$	70	-	-	-
Collector-Emitter saturation voltage	$V_{CE(sat1)}$	$I_C = -100mA, I_B = -10mA$	-	-	-0.2	V
	$V_{CE(sat2)}$	$I_C = -300mA, I_B = -30mA$	-	-	-0.5	
Base-Emitter saturation voltage	$V_{BE(sat1)}$	$I_C = -100mA, I_B = -10mA$	-	-	-1.2	V
	$V_{BE(sat2)}$	$I_C = -300mA, I_B = -30mA$	-	-	-1.7	V
Transition frequency	$f_T$	$V_{CE} = -5V, I_C = -10mA$	-	350	-	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -10V, I_E = 0, f = 1MHz$	-	4	-	pF

Electrical Characteristic Curves

Fig. 1  $P_C - T_a$

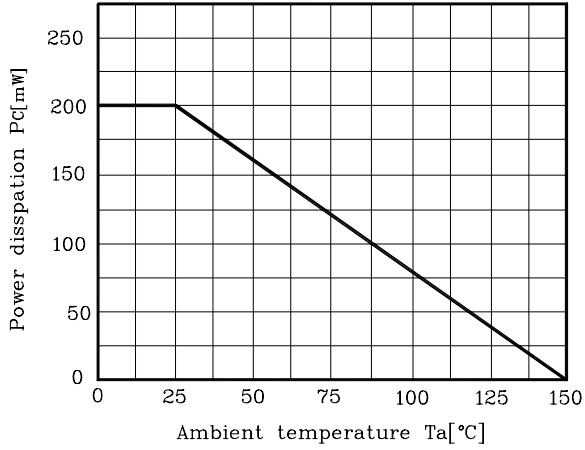


Fig. 2  $I_C - V_{BE}$

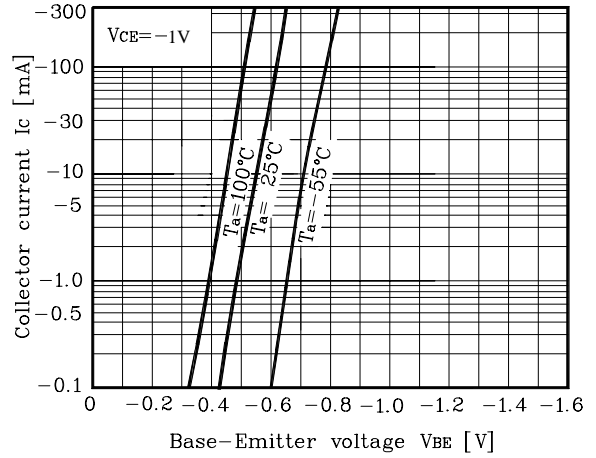


Fig. 3  $h_{FE} - I_C$

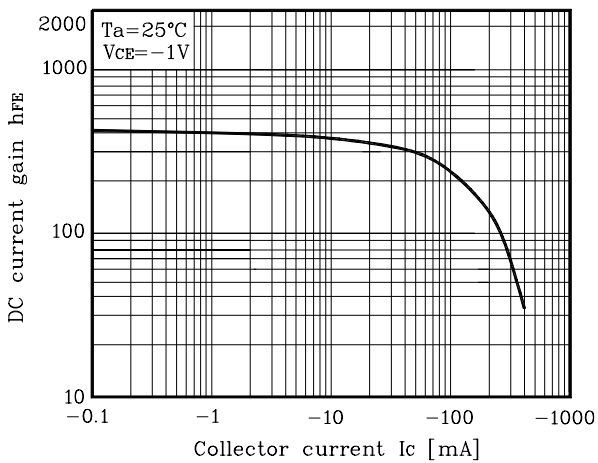


Fig. 4  $I_C - V_{CE}$

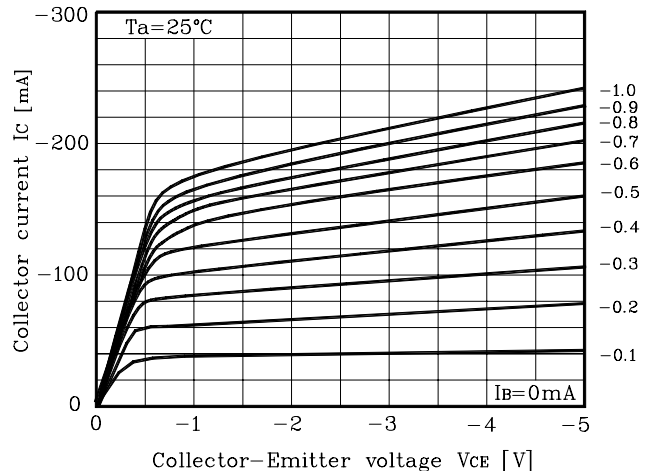


Fig. 5  $V_{CE(sat)} - I_C$

